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Jameco Part Number 45954

TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor
SCHS205C

CD54/74HC4049, CD54/74HC4050

High-Speed CMOS Logic
Hex Buffers, Inverting and Non-Inverting

February 1998 - Revised March 2002

Features

- **Typical Propagation Delay: 6ns at V_{CC} = 5V, C_L = 15pF, T_A = 25°C**
- **High-to-Low Voltage Level Converter for up to V_I = 16V**
- **Fanout (Over Temperature Range)**
  - **Standard Outputs . . . . . 10 LSTTL Loads**
  - **Bus Driver Outputs . . . . . 15 LSTTL Loads**
- **Wide Operating Temperature Range . . . –55°C to 125°C**
- **Balanced Propagation Delay and Transition Times**
- **Significant Power Reduction Compared to LSTTL Logic ICs**
- **HC Types**
  - **2V to 6V Operation**
  - **High Noise Immunity: N_{IL} = 30%, N_{IH} = 30%of V_{CC} at V_{CC} = 5V**

Description

The ’HC4049 and ’HC4050 are fabricated with high-speed silicon gate technology. They have a modified input protection structure that enables these parts to be used as logic level translators which convert high-level logic to a low-level logic while operating off the low-level logic supply. For example, 15-V input pulse levels can be down-converted to 0-V to 5-V logic levels. The modified input protection structure protects the input from negative electrostatic discharge. These parts also can be used as simple buffers or inverters without level translation. The ’HC4049 and ’HC4050 are enhanced versions of equivalent CMOS types.

Ordering Information

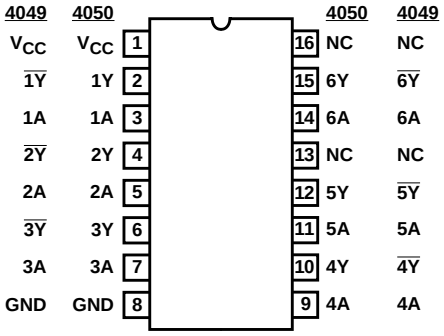
PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC4049F3A	–55 to 125	16 Ld CERDIP
CD74HC4049E	–55 to 125	16 Ld PDIP
CD74HC4049M	–55 to 125	16 Ld SOIC
CD74HC4049NSR	–55 to 125	16 Ld SOP
CD54HC4050F3A	–55 to 125	16 Ld CERDIP
CD74HC4050E	–55 to 125	16 Ld PDIP
CD74HC4050M	–55 to 125	16 Ld SOIC
CD74HC4050NSR	–55 to 125	16 Ld SOP
CD74HC4050PW	–55 to 125	16 Ld TSSOP

NOTES:

1. When ordering, use the entire part number. Add the suffix 96 to the M suffix or the R suffix to the PW package to obtain the variant in the tape and reel.
2. Wafer and die is available which meets all electrical specifications. Please contact your local TI sales office or customer service for ordering information.

Pinout

CD54HC4049, CD54HC4050
(CERDIP)
CD74HC4049, CD74HC4050
(PDIP, SOIC, SOP, TSSOP)
TOP VIEW



CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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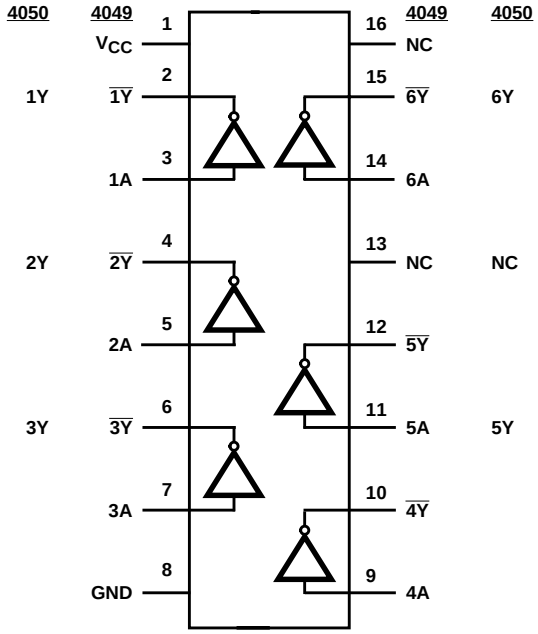
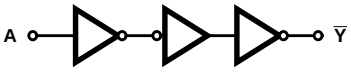
Functional Diagram

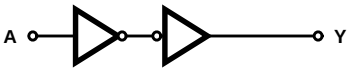


Logic Diagrams

HC4049



HC4050



Absolute Maximum Ratings

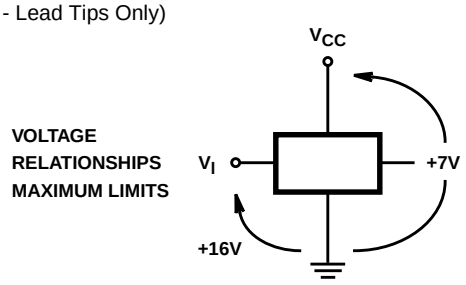
DC Supply Voltage, V_{CC} . . . . . –0.5V to 7V
DC Input Diode Current, I_{IK}
For $V_I < –0.5V$ or $V_I > V_{CC} + 0.5V$ . . . . . ±20mA
DC Output Diode Current, I_{OK}
For $V_O < –0.5V$ or $V_O > V_{CC} + 0.5V$ . . . . . ±20mA
DC Output Source or Sink Current per Output Pin, I_O
For $V_O > –0.5V$ or $V_O < V_{CC} + 0.5V$ . . . . . ±25mA
DC V_{CC} or Ground Current, I_{CC} or I_{GND} . . . . . ±50mA

Operating Conditions

Temperature Range (T_A) . . . . . –55°C to 125°C
Supply Voltage Range, V_{CC}
HC Types . . . . . 2V to 6V
HCT Types . . . . . 4.5V to 5.5V
DC Input or Output Voltage, V_I, V_O . . . . . 0V to V_{CC}
Input Rise and Fall Time
2V . . . . . 1000ns (Max)
4.5V. . . . . 500ns (Max)
6V . . . . . 400ns (Max)

Thermal Information

Package Thermal Impedance, θ_{JA} (see Note 3):
PDIP Package . . . . . 67°C/W
SOIC Package . . . . . 73°C/W
SOP Package . . . . . 64°C/W
TSSOP Package . . . . . 108°C/W
Maximum Junction Temperature (Hermetic Package or Die) . . . 175°C
Maximum Junction Temperature (Plastic Package) . . . . . 150°C
Maximum Storage Temperature Range . . . . . –65°C to 150°C
Maximum Lead Temperature (Soldering 10s) . . . . . 300°C
(SOIC - Lead Tips Only)



CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

3. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

PARAMETER	SYMBOL	TEST CONDITIONS V_I (V)	TEST CONDITIONS I_O (mA)	V_{CC} (V)	25°C MIN	25°C TYP	25°C MAX	–40°C TO 85°C MIN	–40°C TO 85°C MAX	–55°C TO 125°C MIN	–55°C TO 125°C MAX	UNITS
HC TYPES												
High Level Input Voltage	V_{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input Voltage	V_{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output Voltage CMOS Loads	V_{OH}	V_{IH} or V_{IL}	–0.02	2	1.9	-	-	1.9	-	1.9	-	V
			–0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			–0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output Voltage TTL Loads			–4	4.5	3.98	-	-	3.84	-	3.7	-	V
			–5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output Voltage CMOS Loads	V_{OL}	V_{IH} or V_{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	I_I	V_{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	µA
		15	-	6	-	-	±0.5	-	±5	-	±5	
Quiescent Device Current	I_{CC}	V_{CC} or GND	0	6	-	-	2	-	20	-	40	µA

NOTE: For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

Switching Specifications Input t_r, t_f = 6ns

PARAMETER	SYMBOL	TEST CONDITIONS	V_{CC} (V)	25°C			−40°C TO 85°C		−55°C TO 125°C		UNITS
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES											
Propagation Delay, nA to n$\overline{Y}$ HC4049 nA to nY HC4050	t_{PLH}, t_{PHL}	C_L = 50pF	2	-	-	85	-	105	-	130	ns
			4.5	-	-	17	-	21	-	26	ns
			6	-	-	14	-	18	-	22	ns
		C_L = 15pF	5	-	6	-	-	-	-	-	ns
Transition Times (Figure 1)	t_{TLH}, t_{THL}	C_L = 50pF	2	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C_I	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C_{PD}	-	5	-	35	-	-	-	-	-	pF

NOTES:

4. C_{PD} is used to determine the dynamic power consumption, per gate.
5. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = Input Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuit and Waveform

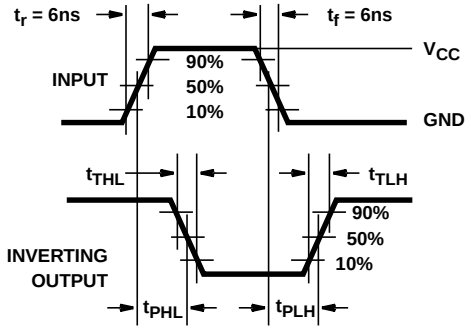


FIGURE 1. HC AND HCU TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

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